MC10H645FN Datasheet

DiGi Electronics Part Number	MC10H645FN-DG
Manufacturer	onsemi
Manufacturer Product Number	MC10H645FN
Description	IC CLK BUFFER 2:9 28PLCC
Detailed Description	Clock Fanout Buffer (Distribution), Multiplexer IC 2:9 28-LCC (J-Lead)

https://www.DiGi-Electronics.com

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
MC10H645FN	onsemi
Series:	Product Status:
-	Obsolete
Type:	Number of Circuits:
Fanout Buffer (Distribution), Multiplexer	1
Ratio - Input:Output:	Differential - Input:Output:
2:9	Yes/Yes
Input:	Output:
TTL	TTL
Voltage - Supply:	Operating Temperature:
4.75V ~ 5.25V	0°C ~ 85°C
Mounting Type:	Package / Case:
Surface Mount	28-LCC (J-Lead)
Supplier Device Package:	Base Product Number:
28-PLCC (11.51x11.51)	MC10H645

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
RoHS non-compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8542.39.0001	

MC10H645

2:1:9 TTL Clock Driver

Description

The MC10H645 is a single supply, low skew, TTL I/O 2:1:9 Clock Driver. Devices in the H600 clock driver family utilizes the PLCC−28 for optimal power and signal pin placement.

The device features a 24 mA TTL output stage with AC performance specified into a 50 pF load capacitance. A 2:1 input Mux is provided on chip to allow for distributing both system and diagnostic clock signals or designing clock redundancy into a system. With the SEL input held LOW the DO input will be selected, while the D1 input is selected when the SEL input is forced HIGH.

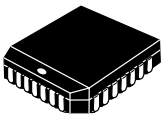
Features

- Low Skew Typically 0.65 ns Within Device
- Guaranteed Skew Spec 1.25 ns Part−to−Part
- Input Clock Muxing
- Differential ECL Internal Design
- Single Supply
- Extra TTL and ECL Power/Ground Pins
- These Devices are Pb−Free and are RoHS Compliant*

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

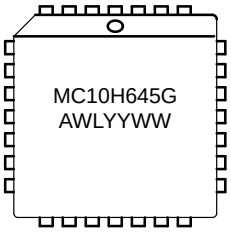
ON Semiconductor®

www.onsemi.com



PLCC
FN SUFFIX
CASE 776

MARKING DIAGRAM



A	= Assembly Location
WL	= Wafer Lot
YY	= Year
WW	= Work Week
G	= Pb−Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

April, 2015 − Rev. 7
Publication Order Number:
MC10H645/D

MC10H645

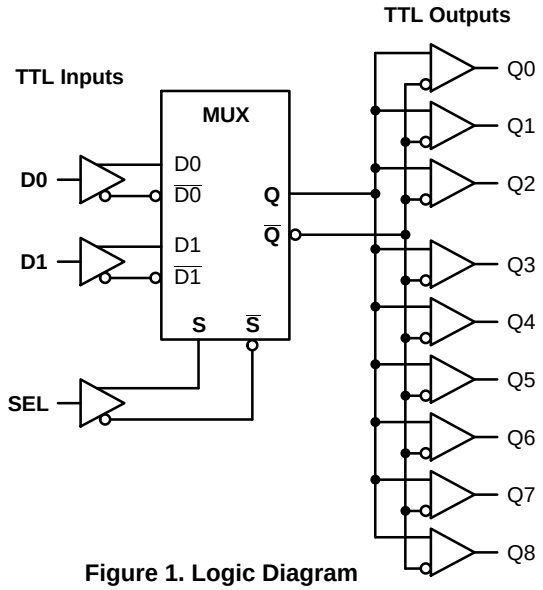


Figure 1. Logic Diagram

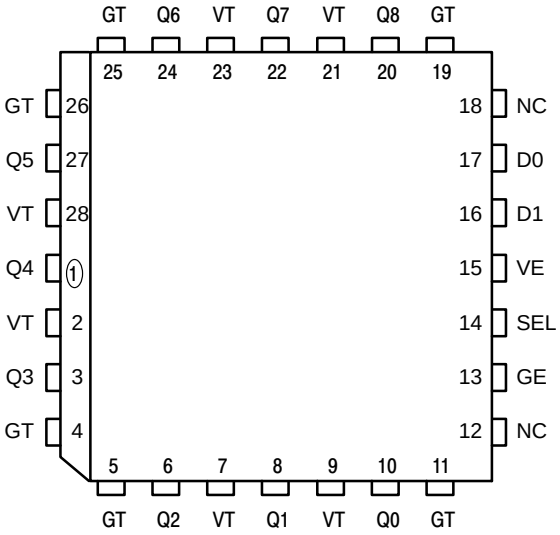


Figure 2. Pinout: 28−Lead PLCC
(Top View)

Table 1. PIN NAMES

PIN	FUNCTION
GT	TTL Ground (0 V)
VT	TTL V_{CC} (+5.0 V)
VE	ECL V_{CC} (+5.0 V)
GE	ECL Ground (0 V)
Dn	TTL Signal Input
Q0 − Q8	TTL Signal Outputs
SEL	TTL Mux Select

Table 2. PIN DESCRIPTIONS

Pin	Symbol	Description	Pin	Symbol	Description
1	Q4	Signal Output (TTL)	15	VE	ECL V_{CC} (+5.0 V)
2	VT	TTL V_{CC} (+5.0 V)	16	D1	Signal Input (TTL)
3	Q3	Signal Output (TTL)	17	D0	Signal Input (TTL)
4	GT	TTL Ground (0 V)	18	NC	No Connection
5	GT	TTL Ground (0 V)	19	GT	TTL Ground (0 V)
6	Q2	Signal Output (TTL)	20	Q8	Signal Output (TTL)
7	VT	TTL V_{CC} (+5.0 V)	21	VT	TTL V_{CC} (+5.0 V)
8	Q1	Signal Output (TTL)	22	Q7	Signal Output (TTL)
9	VT	TTL V_{CC} (+5.0 V)	23	VT	TTL V_{CC} (+5.0 V)
10	Q0	Signal Output (TTL)	24	Q6	Signal Output (TTL)
11	GT	TTL Ground (0 V)	25	GT	TTL Ground (0 V)
12	NC	No Connection	26	GT	TTL Ground (0 V)
13	GE	ECL Ground	27	Q5	Signal Output (TTL)
14	SEL	Select Input (TTL)	28	VT	TTL V_{CC} (+5.0 V)

Table 3. TRUTH TABLE

D0	D1	SEL	Q
L	X	L	L
H	X	L	H
X	L	H	L
X	H	H	H

Table 4. ABSOLUTE RATINGS (Do not exceed)

Symbol	Characteristic	Value	Unit
VE (ECL)	Power Supply Voltage	−0.5 to +7.0	V
VT (TTL)	Power Supply Voltage	−0.5 to +7.0	V
VI (TTL)	Input Voltage	−0.5 to +7.0	V
V_{out}	Disabled 3−State Output	0.0 to V_T	V
T_{stg}	Storage Temperature	−65 to 150	°C
T_{amb}	Operating Temperature	0.0 to +85	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 5. DC CHARACTERISTICS (VT = VE = 5.0 V ±5%)

Symbol	Characteristic		0°C		25°C		85°C		Unit	Condition
			Min	Max	Min	Max	Min	Max		
I_{EE}	Power Supply Current	ECL		30		30		30	mA	VE Pin
I_{CCH}		TTL		30		30		30	mA	Total all VT pins
I_{CCL}				35		35		35	mA	
V_{OH}	Output HIGH Voltage		2.5 2.0		2.5 2.0		2.5 2.0		V	I_{OH} = −3.0 mA I_{OH} = −15 mA
V_{OL}	Output LOW Voltage			0.5		0.5		0.5	V	I_{OL} = 24 mA
I_{OS}	Output Short Circuit Current		−100	−225	−100	−225	−100	−225	mA	V_{OUT} = 0 V

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

Table 6. TTL DC CHARACTERISTICS (VT = VE = 5.0 V ±5%)

Symbol	Characteristic	0°C		25°C		85°C		Unit	Condition
		Min	Max	Min	Max	Min	Max		
V_{IH} V_{IL}	Input HIGH Voltage Input LOW Voltage	2.0	 0.8	2.0	 0.8	2.0	 0.8	V	
I_{IH}	Input HIGH Current		20 100		20 100		20 100	μA	V_{IN} = 2.7 V V_{IN} = 7.0 V
I_{IL}	Input LOW Current		−0.6		−0.6		−0.6	mA	V_{IN} = 0.5 V
V_{OH}	Output HIGH Voltage	2.5 2.0		2.5 2.0		2.5 2.0		V	I_{OH} = −3.0 mA I_{OH} = −24 mA
V_{OL}	Output LOW Voltage		0.5		0.5		0.5	V	I_{OL} = 24 mA
V_{IK}	Input Clamp Voltage		−1.2		−1.2		−1.2	V	I_{IN} = −18 mA
I_{OS}	Output Short Circuit Current	−100	−225	−100	−225	−100	−225	mA	V_{OUT} = 0 V

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

Table 7. AC CHARACTERISTICS (VT = VE = 5.0 V ±5%)

Symbol	Characteristic		0°C Min	0°C Max	25°C Min	25°C Max	85°C Min	85°C Max	Unit	Condition
t_{PLH}	Propagation Delay D_0 to Output Only	Q0−Q8	4.8	5.8	4.8	5.8	5.2	6.2	ns	CL = 50 pF
t_{PLH}	Propagation Delay D_1 to Output		4.8	5.8	4.8	5.8	5.2	6.2	ns	
t_{PHL}	Propagation Delay D_0 to Output D_1 to Output		 4.8 4.8	 5.8 5.8	 4.8 4.8	 5.8 5.8	 5.2 5.2	 6.2 6.2	ns	
t_{skpp}	Part−to−Part Skew D_0 to Output Only			1.0		1.0		1.0	ns	
t_{skwd}*	Within−Device Skew D_0 to Output Only			0.65		0.65		0.65	ns	
t_{PLH}	Propagation Delay SEL to Q	Q0−Q8	4.5	6.5	5.0	7.0	5.2	7.2	ns	CL = 50 pF
t_r t_f	Output Rise/Fall Time 0.8V to 2.0V	Q0−Q8	0.5 0.5	2.5 2.5	0.5 0.5	2.5 2.5	0.5 0.5	2.5 2.5	ns	CL = 50 pF
t_S	Setup Time SEL to D		 1.0		 1.0		 1.0		ns	

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

*Within−Device Skew defined as identical transitions on similar paths through a device.

Table 8. DUTY CYCLE SPECIFICATIONS (0°C ≤ T_A ≤ 85°C; Duty Cycle Measured Relative to 1.5 V)

Symbol	Characteristic		Min	Nom	Max	Unit	Condition
PW	Range of V_{CC} and CL to Meet Min Pulse Width (HIGH or LOW) at f_{out} ≤50MHz	V_{CC} CL PW	4.875 10.0 9.0	5.0	5.125 50.0 11.0	V pF ns	All Outputs

ORDERING INFORMATION

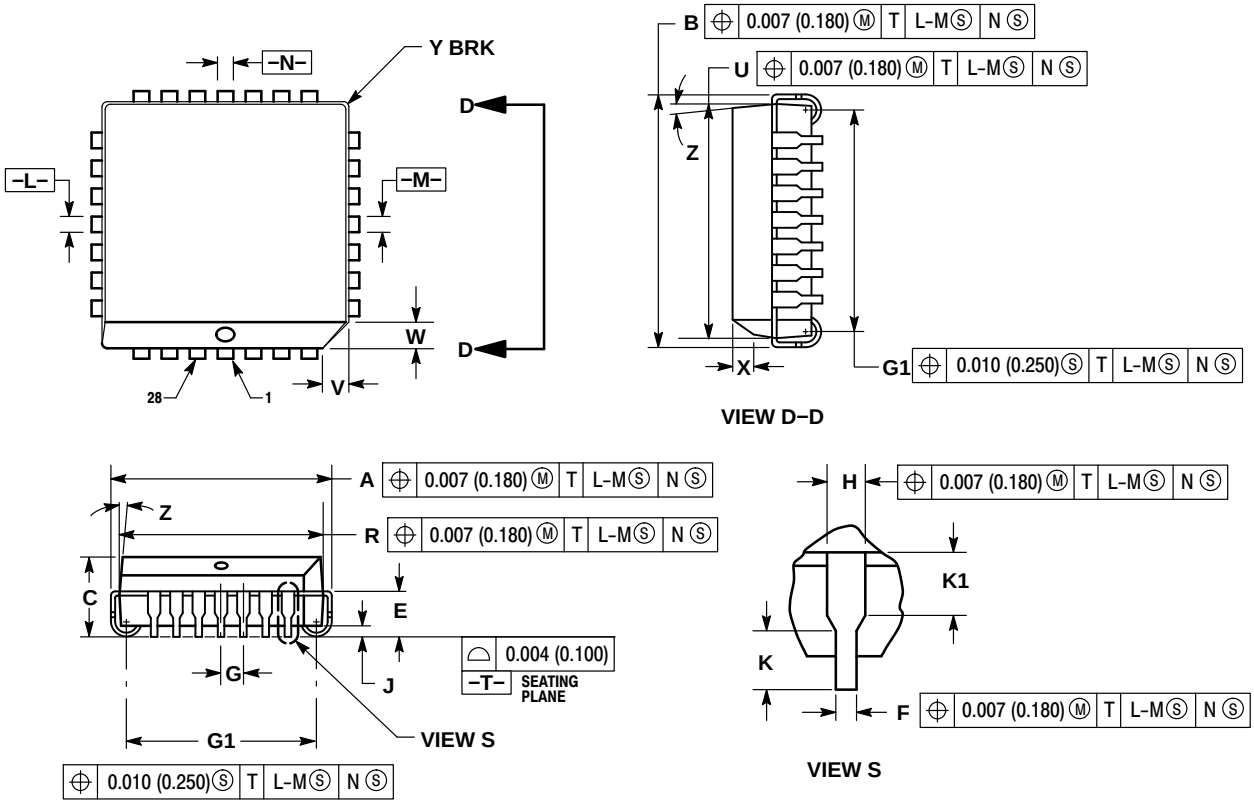
Device	Package	Shipping†
MC10H645FNG	PLCC−28 (Pb−Free)	37 Units / Rail
MC10H645FNR2G	PLCC−28 (Pb−Free)	500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MC10H645

PACKAGE DIMENSIONS

PLCC−28
FN SUFFIX
CASE 776−02
ISSUE E



NOTES:
1. DATUMS −L−, −M−, AND −N− DETERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.
2. DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM −T−, SEATING PLANE.
3. DIMENSIONS R AND U DO NOT INCLUDE MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.
4. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
5. CONTROLLING DIMENSION: INCH.
6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
7. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.485	0.495	12.32	12.57
B	0.485	0.495	12.32	12.57
C	0.165	0.180	4.20	4.57
E	0.090	0.110	2.29	2.79
F	0.013	0.021	0.33	0.53
G	0.050 BSC		1.27 BSC	
H	0.026	0.032	0.66	0.81
J	0.020	---	0.51	---
K	0.025	---	0.64	---
R	0.450	0.456	11.43	11.58
U	0.450	0.456	11.43	11.58
V	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
X	0.042	0.056	1.07	1.42
Y	---	0.020	---	0.50
Z	2°	10°	2°	10°
G1	0.410	0.430	10.42	10.92
K1	0.040	---	1.02	---

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303−675−2175 or 800−344−3860 Toll Free USA/Canada
Fax: 303−675−2176 or 800−344−3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800−282−9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81−3−5817−1050

ON Semiconductor Website: **www.onsemi.com**

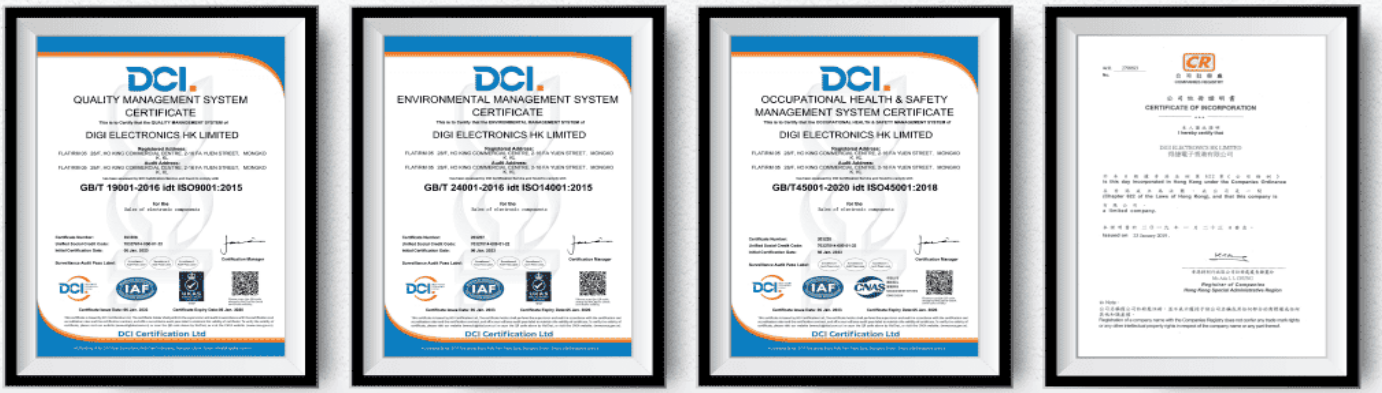
Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

MC10H645/D

OUR CERTIFICATE

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we striciy control the quality of products and services. Welcome your RFQ to Email: Info@DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.